# High Performance Balanced Photodetector (BPD-1)



- High sensitivity; selectable 5 V/mW and 10 V/mW
- ► Wide bandwidth; DC to 400 MHz
- Very low noise, NEP <5 pW/ $\sqrt{Hz}$
- Ideal for low-noise or high-speed detection, dualbalanced or single-ended
- Optimized for high-speed swept source OCT with low harmonic distortion and low group delay
- High speed dual balanced output and positive and negative monitor outputs
- Small body size
- Easy installation with optional flange or post mount

The BPD-1 differential photodetector is a DC to 400 MHz dual balanced photodetector optimized for swept source OCT (SS-OCT) imaging systems. By careful design, the BPD-1 supports high speed SS-OCT, minimizing factors that other detectors do not even specify, such as harmonic distortion and group delay. Importantly, with high speed and low noise applications such as with new generation lasers, the laser noise can be an order of magnitude below older lasers, so the detector may limit the overall system noise performance and resulting image quality. The NEP of less than 5 pW/Hz is exemplary, and is roughly 75% lower than comparable devices.

Since signal levels in SS-OCT systems can vary from setup to setup, a selectable 5 V/mW or 10 V/mW gain can be selected with little performance impact. Selectable gain allows the signal level to be adjusted to maximize the use of the analog-to-digital conversion dynamic range, avoiding loss of effective bits of resolution.

The BPD-1 is configured as a dual-balanced receiver by subtracting the two optical input signals from each other, resulting in the cancellation of common mode noise. Dual balanced detection allows small changes in the signal path to be extracted from the interfering noise floor.

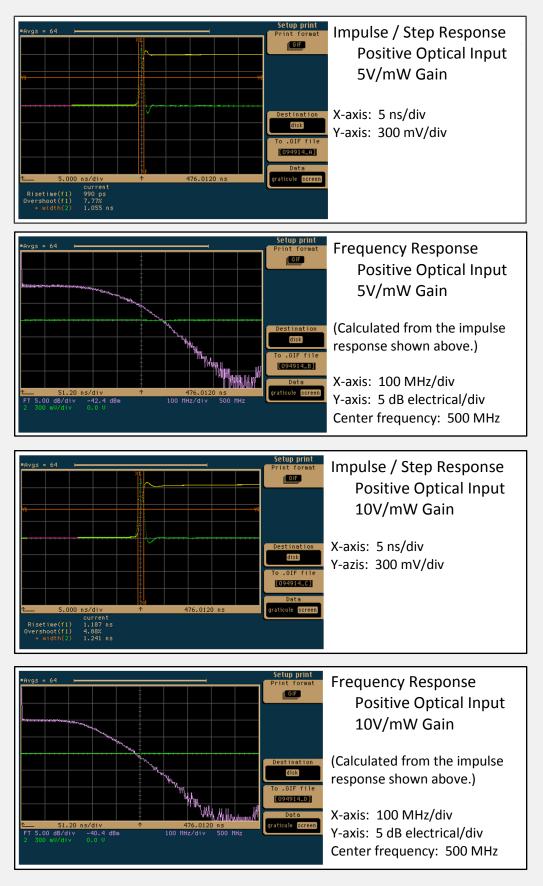
The detector consists of two balanced photodiodes and an ultra-low-noise, high-speed transimpedance amplifier. Matching the two photodiodes results in an excellent common mode rejection ratio (CMRR), leading to better noise reduction. The detector a balanced RF-output from the transimpedance amplifier, and the Monitor+ and Monitor-ports allow the response of each photodiode to be observed individually to verify performance of each leg independently.

The detectors are fiber coupled with SMF-28 fiber, reducing the chance of image artifacts that can occur with detector coupling optics.

Insight has worked with one of the world's top analog design teams at Graviton in Japan to create the BPD-1. Graviton, and their founder and top designer, Nagatomo-san, have created some of the world's best audio amplifiers for decades, Nagatomo has also built some of the world's best photodetector devices, including precision devices up to 8 GHz. By careful attention to parts, layout, topology and design, critical factors such as parasitic capacitance is reduced by multiples, supporting overall performance substantially better than other devices.

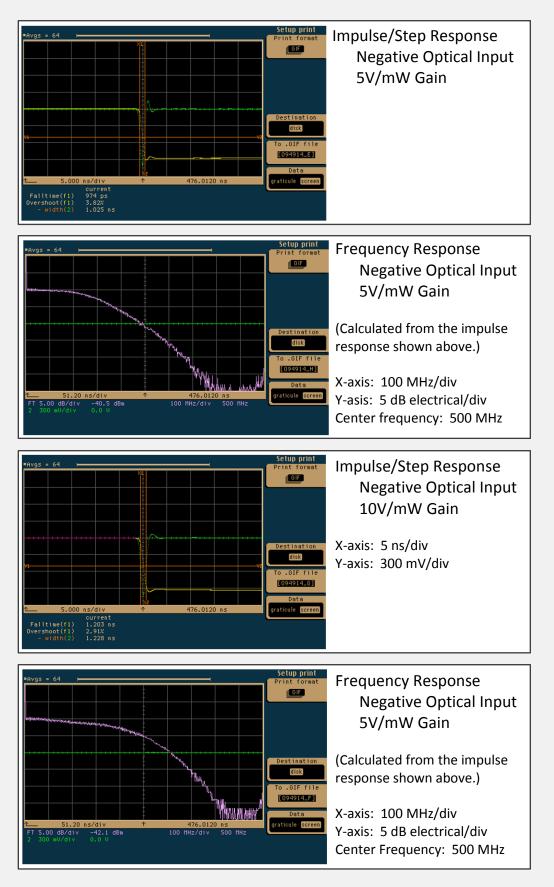


# Typical Performance Data



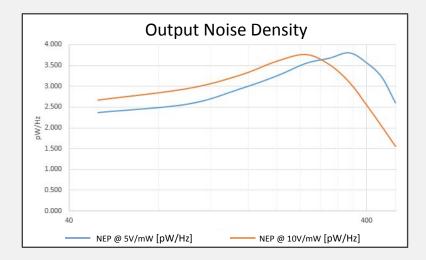


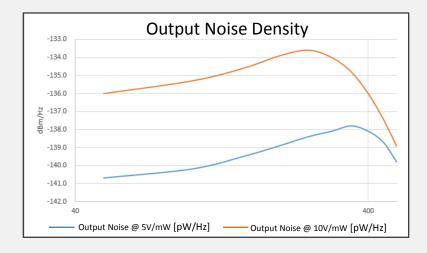
# Typical Performance Data (cont.)

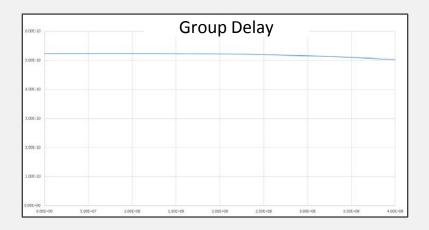




# Typical Performance Data (cont.)



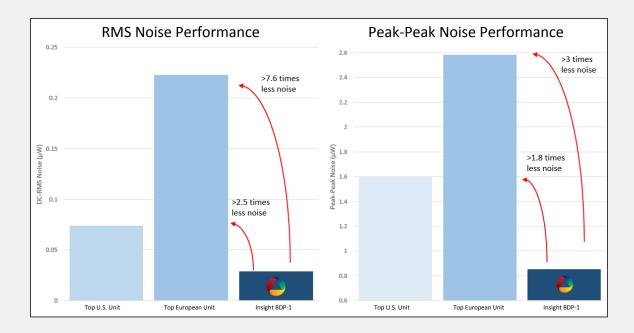






Typical Performance Data (cont.)

Top/Euro@3.5V/m\ 478 nW RMS, 3.67	Dillion (C				Top/Euro@3.5V/mW	⁺Ţı
Top/US@10V/mW 173 nW RMS, 1.96	µW pk-pk	u and participation and a participation The State Construction of the State Construction		inessenningen er en en senningen Hieroriensken of her et konstansen	Top/US@10V/mW	<b>4</b> <u>1</u> 2
Insight@10V/mW 110 nW RMS, 1.18	µW pk-pk				Insight@10V/mW	<b>4</b> 13
Insight@5V/mW 129 nW RMS, 1.65		0 ms/ 🕠 🔿 T	0.0 s	• • •	Insight@5V/mW	<b>1</b> 4 ↑
Measurements Markers Lo		es				
Current 1. Mean 1. Min 1. Max 1. Std Deviation 17	DCVrms(1) .81874 mV .79403 mV .73279 mV .84919 mV 7.1482 µV .087 k	DCVrms(2) 1.84069 mV 1.84638 mV 1.78580 mV 1.91211 mV 18.8375 µV 2.087 k	DCVrms(3) 1.36470 mV 1.27924 mV 1.15602 mV 1.40431 mV 36.0836 µV 2.087 k	DCVrms(4) 896.941 µV 913.234 µV 815.600 µV 1.00811 mV 38.4980 µV 2.084 k	V avg(3) 776.052 µV 647.093 µV 433.968 µV 870.092 µV 63.1524 µV 2.087 k	
Current 11 Mean 12 Min 11 Max 13 Std Deviation 38	V p-p(1) 1.508 mV 2.0599 mV 1.054 mV 3.869 mV 33.11 µV .087 k	V p-p(2) 20.092 mV 19.5894 mV 17.985 mV 22.126 mV 577.93 μV 2.087 k	V p-p(3) 11.866 mV 11.8896 mV 10.672 mV 13.600 mV 417.01 µV 2.087 k	V p-p(◀) 7.968 mV 8.33910 mV 7.169 mV 11.112 mV 449.96 µV 2.084 k	Scope noise floo 1.07 mV	or



(Data with scope base noise removed.)

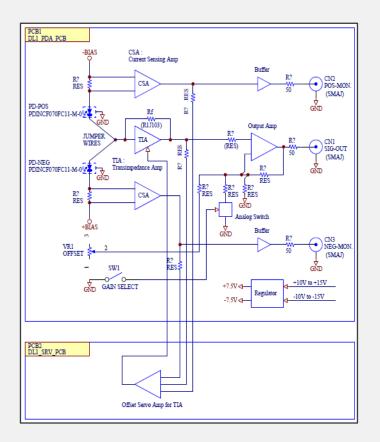


# Specifications **PRELIMINARY**

ltem	Conditions	Value (Design Target)
Detector type		InGaAs PIN photodiode
Optical inputs		FC/APC
Acceptable fiber		Single mode fiber
Operating wavelength		950 nm to 1650 nm
Responsivity of PD	1310 nm; FC/APC	0.85 mA/mW
Active detector diameter		0.075 mm
Optical back reflection		Less than -40 dB
PD damage threshold		8 mW
RF output impedance		50 ohm
RF output bandwidth	50 Ω load	DC to 400 MHz @ 5 V/mW; DC to 300 MHz @ 10V/mW
RF output conversion gain	1310 nm; 50 Ω load	5 V/mW; 10 V/mW; switchable
RF output CW saturation power	1310 nm; 5V/mW; 50 Ω load	400 μW (-4 dBm)
RF output voltage swing	50 ohm load Hi-Z load	±2 V ±4 V
RF output coupling		DC Coupling
RF output connector		SMA Jack
NEP	DC to 100 MHz; 50 Ω load	< 5 pW/√Hz @ 5 V/mW; < 4 pW/√Hz @ 10 V/mW
RF output voltage noise	DC to 12.4GHz, 50 Ω load	< 0.7 mV RMS @ 5 V/mW; < 1.1 mV RMS @ 10 V/mW;
RF output offset voltage	50 Ω load	Within ±0.1 mV
Common mode rejection		>25 dB
Monitor output impedance		50 Ω
Monitor output bandwidth	Hi-Z load	DC to 100 kHz
Monitor output conversion gain	1310 nm; Hi-Z load	10 V/mW; 20 V/mW; switchable
Monitor output voltage swing	50 ohm load Hi-Z load	±5 V ±10 V
Monitor output voltage noise	DC to 12.4 GHz; 50 $\Omega$ load	Less than 0.6 mV RMS
Monitor output offset voltage	Hi-Z load	Within ±0.1 mV
DC supply voltage		±10V to ±15V or 0-20V to 0-30V
AC accessory supply	Input	110-240 VAC
Consumption current	50 Ω load; full swing	Less than ±300 mA
Operating temperature		0 °C to 40 °C
Storage temperature		-40 °C to 70 °C
Dimensions (width x depth x height)	Without connectors; no flange	60 mm x 60 mm x 23 mm
Dimensions (width x depth x height)	Without connectors; flange	60 mm x 76 mm x 23 mm
Mounting		Dual flange or optical post
Included accessories		Power supply, flange mount
Weight	With flange	0.2 kg (<0.5 lbs)



# Block Diagram

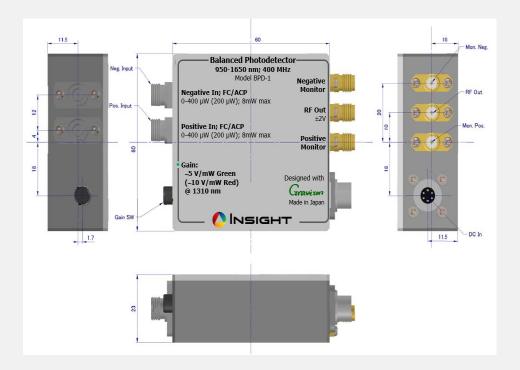


# **Performance Characteristics**

F	DC Transimpedance	Real part of the	Im part of the	Transimpedance	Response [dB		
Frequency [Hz]	[ohms]	denominator	denominator	[ohms]2	ohms]	Phase [deg]	Group Delay [s]
1.00E+03	9.66E+03	1.00E+00	3.29E-06	9655.17-0.03i	79.70	-0.0002	5.23E-10
1.50E+03	9.66E+03	1.00E+00	4.93E-06	9655.17-0.05i	79.70	-0.0003	5.23E-10
2.20E+03	9.66E+03	1.00E+00	7.23E-06	9655.17-0.07i	79.70	-0.0004	5.23E-10
3.30E+03	9.66E+03	1.00E+00	1.09E-05	9655.17-0.1i	79.70	-0.0006	5.23E-10
4.70E+03	9.66E+03	1.00E+00	1.55E-05	9655.17-0.15i	79.70	-0.0009	5.23E-10
6.80E+03	9.66E+03	1.00E+00	2.24E-05	9655.17-0.22i	79.70	-0.0013	5.23E-10
1.00E+04	9.66E+03	1.00E+00	3.29E-05	9655.17-0.32i	79.70	-0.0019	5.23E-10
1.50E+04	9.66E+03	1.00E+00	4.93E-05	9655.17-0.48i	79.70	-0.0028	5.23E-10
2.20E+04	9.66E+03	1.00E+00	7.23E-05	9655.17-0.7i	79.70	-0.0041	5.23E-10
3.30E+04	9.66E+03	1.00E+00	1.09E-04	9655.17-1.05i	79.70	-0.0062	5.23E-10
4.70E+04	9.66E+03	1.00E+00	1.55E-04	9655.17-1.49i	79.70	-0.0089	5.23E-10
6.80E+04	9.66E+03	1.00E+00	2.24E-04	9655.17-2.16i	79.70	-0.0128	5.23E-10
1.00E+05	9.66E+03	1.00E+00	3.29E-04	9655.17-3.18i	79.70	-0.0188	5.23E-10
1.50E+05	9.66E+03	1.00E+00	4.93E-04	9655.17-4.76i	79.70	-0.0283	5.23E-10
2.20E+05	9.66E+03	1.00E+00	7.23E-04	9655.17-6.99i	79.70	-0.0415	5.23E-10
3.30E+05	9.66E+03	1.00E+00	1.09E-03	9655.16-10.48i	79.70	-0.0622	5.23E-10
4.70E+05	9.66E+03	1.00E+00	1.55E-03	9655.16-14.92i	79.70	-0.0886	5.23E-10
6.80E+05	9.66E+03	1.00E+00	2.24E-03	9655.14-21.59i	79.70	-0.1281	5.23E-10
1.00E+06	9.66E+03	1.00E+00	3.29E-03	9655.1-31.75i	79.70	-0.1884	5.23E-10
1.50E+06	9.66E+03	1.00E+00	4.93E-03	9655.02-47.63i	79.70	-0.2826	5.23E-10
2.20E+06	9.66E+03	1.00E+00	7.23E-03	9654.84-69.85i	79.70	-0.4145	5.23E-10
3.30E+06	9.66E+03	1.00E+00	1.09E-02	9654.42-104.78i	79.70	-0.6218	5.23E-10
4.70E+06	9.66E+03	1.00E+00	1.55E-02	9653.64-149.22i	79.69	-0.8856	5.23E-10
6.80E+06	9.66E+03	1.00E+00	2.24E-02	9651.97-215.87i	79.69	-1.2813	5.23E-10
1.00E+07	9.66E+03	1.00E+00	3.29E-02	9648.25-317.4i	79.69	-1.8842	5.23E-10
1.50E+07	9.66E+03	9.99E-01	4.93E-02	9639.59-475.89i	79.69	-2.8263	5.23E-10
2.20E+07	9.66E+03	9.98E-01	7.23E-02	9621.67-697.34i	79.69	-4.1453	5.23E-10
3.30E+07	9.66E+03	9.96E-01	1.09E-01	9579.87-1043.76i	79.68	-6.2181	5.23E-10
4.70E+07	9.66E+03	9.92E-01	1.55E-01	9502.73-1480.66i	79.66	-8.8563	5.23E-10
6.80E+07	9.66E+03	9.83E-01	2.24E-01	9337.41-2123.79i	79.62	-12.8139	5.23E-10
1.00E+08	9.66E+03	9.64E-01	3.29E-01	8974.62-3062.83i	79.54	-18.8436	5.23E-10
1.50E+08	9.66E+03	9.18E-01	4.93E-01	8160.67-4384.6i	79.34	-28.2484	5.23E-10
2.20E+08	9.66E+03	8.24E-01	7.23E-01	6616.84-5810.86i	78.90	-41.2894	5.21E-10
3.30E+08	9.66E+03	6.04E-01	1.09E+00	3779.38-6794.84i	77.81	-60.9166	5.13E-10
4.00E+08	9.66E+03	4.18E-01	1.32E+00	2116.91-6667.94i	76.90	-72.3866	5.03E-10



#### Physical Dimensions (with and without user-detachable flange)



# **Ordering Information**

Model	Wavelength	BW	Gain	Saturation/ Max Power	NEP	Delivery
BPD-1	980-1650 nm	400MHz (300MHz)	5 V/mW (10 V/mW)	400 μW/8 mW	< 5 pW/vHz @ 5 V/mW < 4 pW/vHz @ 10 V/mW	2 days ARO after 12/15/14

\* User-detachable flange included.

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